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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

Shieh, et al.

Docket No.:

TSM02-1241

Serial No.:

10/721,979

Art Unit:

2812

Filed:

November 25, 2003

Examiner:

TBD

For:

Method of Fabricating Semiconductor Device with Separate Periphery and

Cell Region Etching Steps

Certificate of Mailing via First Class Mail (37 C.F.R. § 1.8(a))

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Certificate of Mailing via First Class Mail (1 page) Information Disclosure Statement (1 page) PTO/SB/08a with 4 References Cited (1 page) Copy of 2 Cited References Return Postcard

Respectfully submitted,

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Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

The Applicant wishes to bring to the attention of the Patent and Trademark Office the information noted on the enclosed form PTO/SB/08A that may be considered material to the examination of the above-identified application.

No fee is due at this time, as this Information Disclosure Statement is being filed pursuant to 37 C.F.R. § 1.97(b)(3), before the mailing of a first Office action on the merits.

Cite numbers A-B are newly cited prior art being filed under the waived requirement of 37 CFR 1.98 (a)(2)(i) dated July 11, 2003, therefore, copies of these U.S. patents are not included.

Respectfully submitted,

Date

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PTO/SB/08a (08-03)

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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Complete if Known		
				Application Number	10/721,979	
				Filing Date	11/25/2003	
				First Named Inventor	Shieh, et al.	
	(Use as many sheets	as necessary)		Art Unit	2812	
				Examiner Name	TBD	
Sheet	11	of	1	Attorney Docket Number	TSM02-1241	

U.S. PATENT DOCUMENTS						
Examiner Initials*	Cite No.1	Document Number Number - Kind Code ^{2 (d known)}	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant	
	A	US-6,448,608 B1	09-10-2002	Pham, et al.	Figures Appear	
~ <u></u>	В	US-6,559,501 B2	05-06-2003	Sung, et al.		
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FOREIGN PATENT DOCUMENTS						
Examiner	Cite	Foreign Patent Document	Publication Date	Name of Patentee or	Pages, Columns, Lines,	
	1	Country Code ³ - Number ⁴ - Kind Code ⁵ (if known)	MM-DD-YYYY	Applicant of Cited Document	Where Relevant Passages or Relevant Figures Appear	T ⁶
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NON PATENT LITERATURE DOCUMENTS						
Examin Initials*	er Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²			
	С	OEHRLEIN, G.S., et al., "Surface Science Issues in Plasma Etching," [on-line] IBM Journal of Research and Development, Vol. 43, 1/2 (1999), Retrieved From: http://www.research.ibm.com/journal/rd/431/oehrlein.html				
	D	"Technical Comparison of Floating Gate Reprogrammable Nonvolatile Memories," Technical Paper, Silicon Storage Technology, Inc. (November 2001) pp. 1-8.				

Examiner	Date	
Signature	Considered	
	Considered	

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. 'Applicant's unique citation designation number (optional). 'See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. 'Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). 'For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. 'Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. 'Applicant is to place a check mark here if English language Translation is attached.

Translation is attached.

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